

L Number	Hits	Search Text	DB	Time stamp
1	1	("6077752").PN.	USPAT	2004/06/17 11:10
3	0	((("6077752").PN.) and (buried adj collector)	USPAT	2004/06/17 11:10
2	1	((("6077752").PN.) and (collector)	USPAT	2004/06/17 11:10
4	1	("6261964").PN.	USPAT	2004/06/17 11:43
-	5	((("6255183") or ("6077752") or ("5616508") or ("5592017") or ("5502330")).PN.	USPAT	2004/06/16 14:42
-	3	((("5266504") or ("5213989") or ("4988632")).PN.	USPAT	2004/06/16 14:43
-	43	amorphous and (silicon-germanium) and monocrystalline and dielectric and pattern and etch and heat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/16 14:44
-	4	amorphous and (silicon-germanium) and monocrystalline and dielectric and pattern and etch and heat and crystallize	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/16 14:44
-	33	amorphous and (silicon-germanium) and monocrystalline and dielectric and pattern and etch and heat and implant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/16 14:44
-	0	amorphous and (silicon-germanium) and monocrystalline and dielectric and pattern and etch and heat and (implant with germanium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/16 14:44
-	0	amorphous and (silicon-germanium) and monocrystalline and dielectric and pattern and etch and heat and implant and dope	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/16 14:45
-	7	amorphous and (silicon with germanium) and (monocrystalline adj silicon) and dielectric and pattern and etch and heat and implant and dope	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/16 14:46